

**2-PHASE HALF-WAVE HIGH VOLTAGE MOTOR PRE-DRIVER****AM4406****General Description**

The AM4406 is a 2-phase, half-wave motor predriver fabricated for fan motors. This IC is equipped with lock shutdown, automatic restart and rotation detection (RD) function. The lock shutdown function turns off the output current when the motor is under lock condition. And when the motor is unlocked, the IC will automatically restart and allow DC fan to run. In addition, the RD function is to detect the motor status.

The AM4406 is available in SOIC-8 package.

Features

- Hall Inputs with a Hysteresis
- Lock Shutdown and Automatic Restart
- Rotation Detection (RD) Output
- Supply Voltage: 4 to 28V
- Output Current: 70mA Max.
- Operating Temperature: -30 to 85°C

Applications

- High Voltage, High Current Brushless DC Fan
- Power Supply and Switchboards
- Communications Facilities
- Industrial Equipment

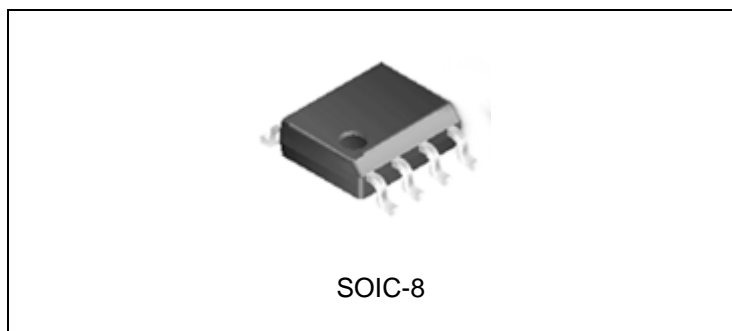


Figure 1. Package Type of AM4406

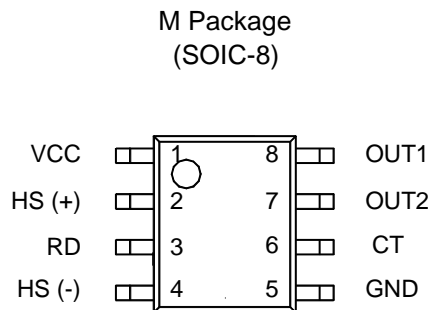
**2-PHASE HALF-WAVE HIGH VOLTAGE MOTOR PRE-DRIVER****AM4406****Pin Configuration**

Figure 2. Pin Configuration of AM4406 (Top View)

Pin Description

Pin Number	Pin Name	Function
1	VCC	Power supply
2	HS (+)	Hall input (+)
3	RD	Rotation detection
4	HS (-)	Hall input (-)
5	GND	Ground
6	CT	Timing capacitor
7	OUT2	Driver output 2
8	OUT1	Driver output 1



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Functional Block Diagram

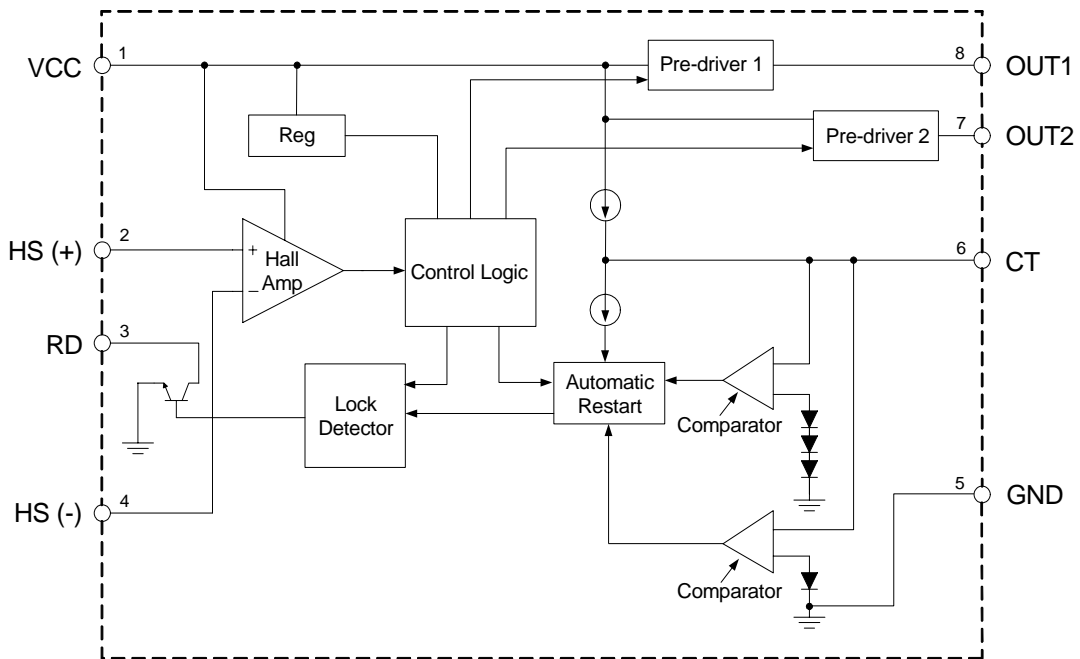


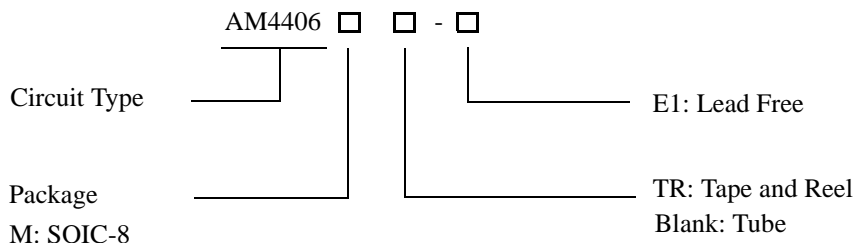
Figure 3. Functional Block Diagram of AM4406



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Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
SOIC-8	-30 to 85°C	AM4406M-E1	AM4406M	Tube
		AM4406MTR-E1	AM4406M	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**2-PHASE HALF-WAVE HIGH VOLTAGE MOTOR PRE-DRIVER****AM4406****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	30	V
Output Current	I_{OUT}	70	mA
Power Dissipation	P_D	550 (Note 2)	mW
Storage Temperature Range	T_{STG}	-55 to 125	°C
ESD (Human Body Model)	ESD	3000	V
ESD (Machine Model)	ESD	300	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: Reduced by 5.5mW/°C when T_A is over 25°C.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	4	28	V
Hall Input Voltage (+) (Note 3)	$V_{HS}(+)$	1.0	$V_{CC}-0.5$	V
Hall Input Voltage (-) (Note 3)	$V_{HS}(-)$	1.0	$V_{CC}-0.5$	V
Operating Temperature	T_A	-30	85	°C

Note 3: Hall input voltage range includes the amplitude of signal.

**2-PHASE HALF-WAVE HIGH VOLTAGE MOTOR PRE-DRIVER****AM4406****Electrical Characteristics**(V_{CC}=12V, T_A=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Supply Current	I _{CC}	No load		3.2	5.0	mA
Hall Amplifier Input Hysteresis (+)	V _{HYS} (+)	Zero to peak including offset and hysteresis	3		15	mV
Hall Amplifier Input Hysteresis (-)	V _{HYS} (-)	Zero to peak including offset and hysteresis	-3		-15	mV
CT Charge Current	I _{CHG}	V _{CT} =1.5V	2	3.45	5.25	μA
CT Discharge Current	I _{DHG}	V _{CT} =1.5V	0.35	0.8	1.45	μA
CT Charge and Discharge Ratio	R _{CD}	I _{CHG} /I _{DHG}	3	4.5	8	
CT Clamp Voltage	V _{CL}		2.2	2.6	3	V
CT Comparator Voltage	V _{CP}		0.4	0.6	0.8	V
OUT1 High Level Voltage	V _{OH1}	I _{OUT1} =10mA	10	10.5		V
OUT2 High Level Voltage	V _{OH2}	I _{OUT2} =10mA	10	10.5		V
RD Output Low Level Voltage	V _{RDL}	I _{RD} =5mA		0.2	0.5	V
RD Current Capacity	I _{RD}	V _{RD} =2V	8	18		mA



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Typical Performance Characteristics

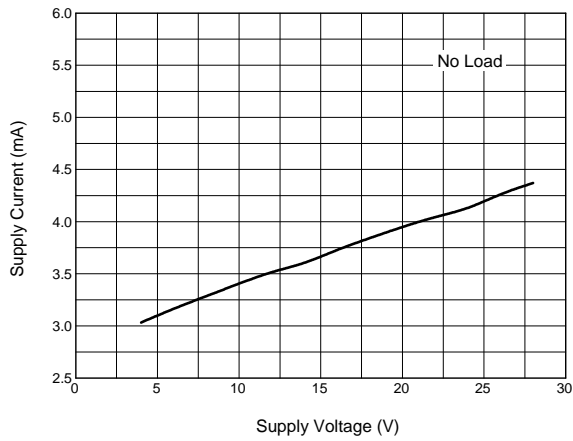


Figure 4. Supply Current vs. Supply Voltage

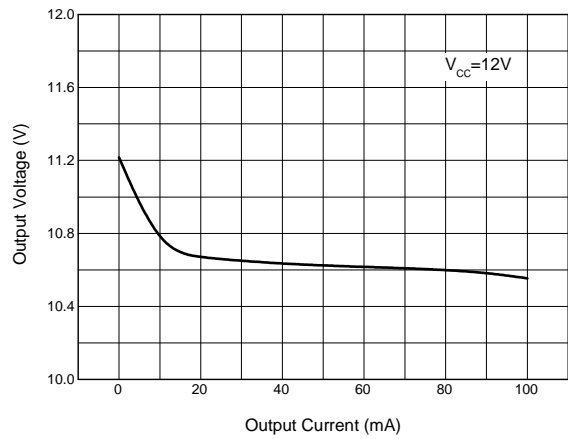


Figure 5. Output Voltage vs. Output Current

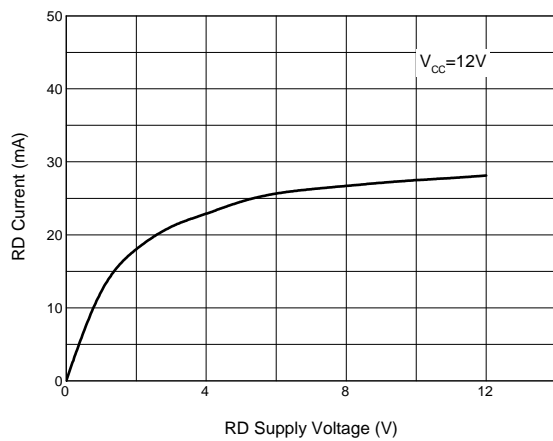


Figure 6. RD Current vs. RD Supply Voltage

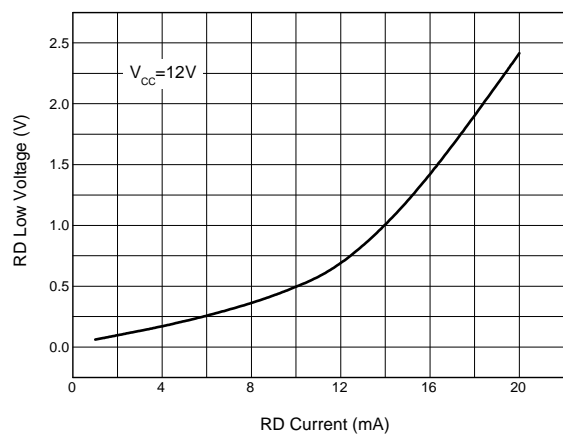


Figure 7. RD Low Voltage vs. RD Current



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Typical Performance Characteristics (Continued)

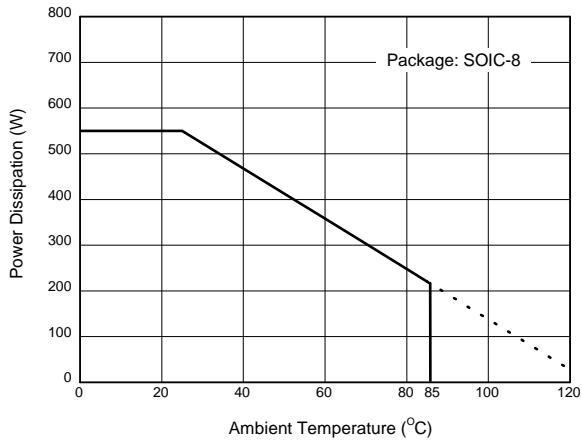
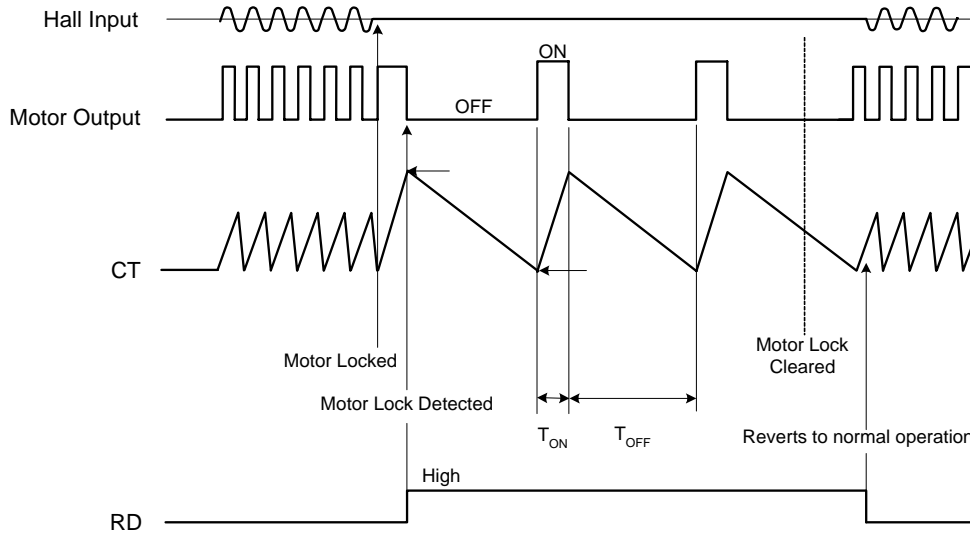


Figure 8. Power Dissipation vs. Ambient Temperature



Operating Diagram



Note 4: Automatic restart is performed in the following manner. A motor lock condition is detected when the hall signal stops switching. The output is ON when CT pin is being charged. C2 is the external capacitor of the CT pin. Output ON time and OFF time are determined by the capacitance of C2.

Note 5: RD pin is ON during normal operation, and OFF when the motor is locked. It is an open collector output pin.

$$T_{ON} = \frac{C2 * (V_{CL} - V_{CP})}{I_{CHG}} \text{ (Sec.)}$$

$$T_{OFF} = \frac{C2 * (V_{CL} - V_{CP})}{I_{DHG}} \text{ (Sec.)}$$

Note 6: The RD pin may maintain HIGH level for a few hundred milliseconds when the power is turn on.

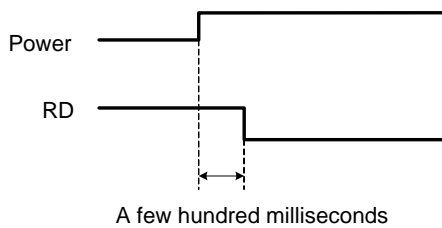


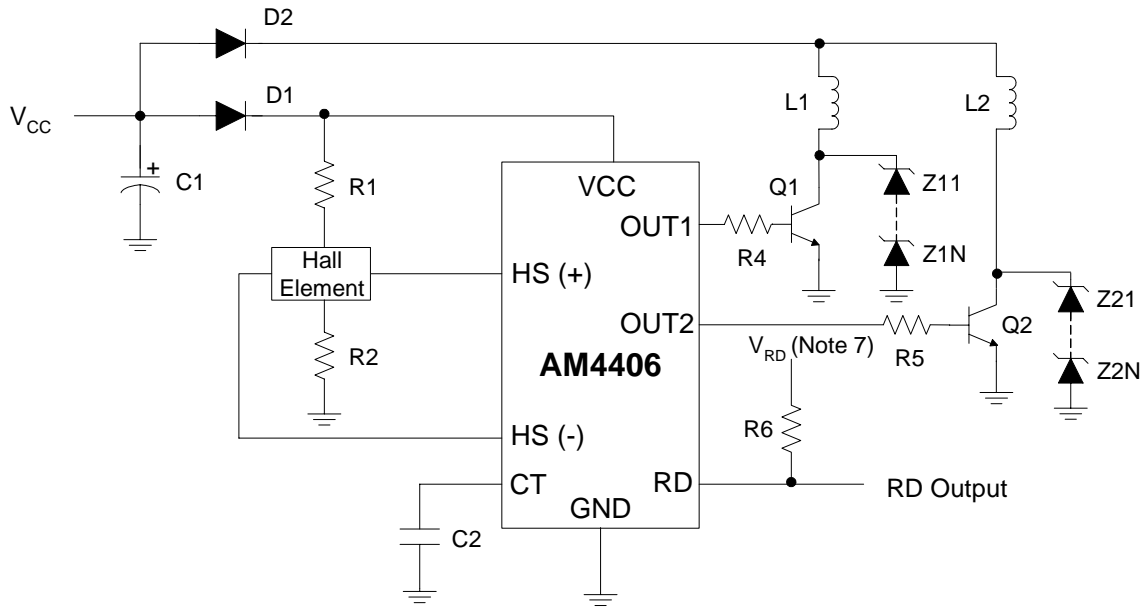
Figure 9. Control Timing Diagram of AM4406



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Typical Application



Note 7: V_{RD} should be equal or smaller than V_{CC} .

Figure 10. Typical Application of AM4406



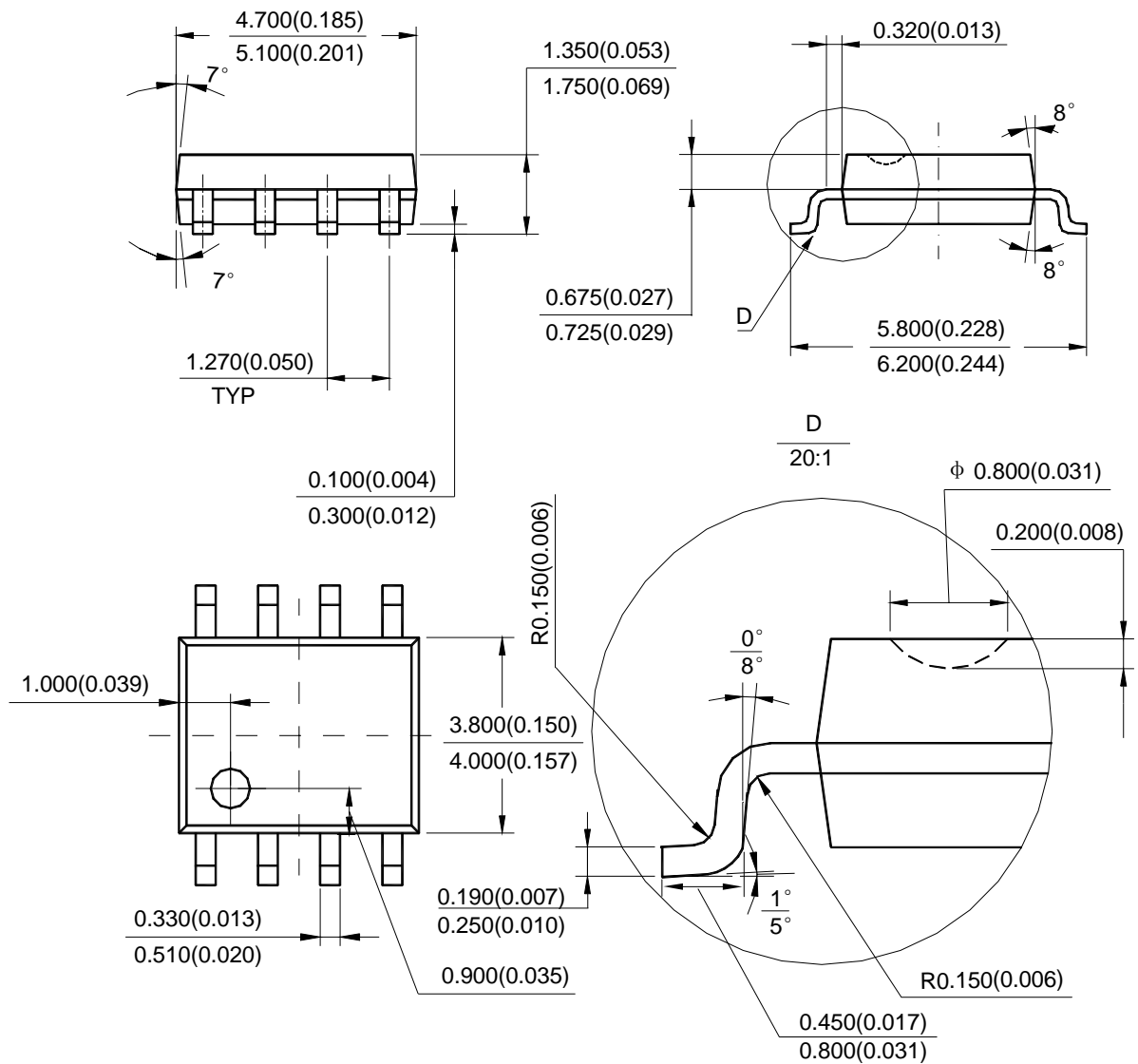
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Mechanical Dimensions

SOIC-8

Unit: mm(inch)





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